

NSM2402AT V2.0

QS-EP00-010

NSM2402AT Top-Inlet Analog Silicon Microphone Specification

Rev. 2.0



1. GENERAL DESCRIPTION

NSM2402AT is a "slim-bodied" Silicon Microphone with analog output and top inlet for sound input. It is a cost-effective alternative to traditional electret condenser microphone (ECM). Provided on tap-and-reel, it is ideally suited for high volume applications. And it can be processed directly to customer's PCB using standard automatic pick-and-place equipment and surface mounted via standard solder reflow equipment.

NSM0402AT can be used in (but not limited to) the following applications:

- 1. Portable communication device
- 2. Notebook and desktop
- 3. Headphone and headset accessories

2. ABSOLUTE MAXIMUM RATINGS

Supply voltage: VDD to C	GND0.3V~5V
ESD Tolerance	
The Lid Mode	8kV
The I/O Pin Mode	4kV

TEMPERATURE CHARACTERISTICS					
ParameterConditionsMinTypMaxUnit					
Operating Temperature		-40		+85	$^{\circ}\!$
Store on Tommeroture	Solder on PC board	-40		+105	°C
Storage Temperature	In Tape and Reel	-10		+50	°C

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3. ACOUSTIC & ELECTRICAL SPECIFICATIONS

Unless otherwise specified, test conditions are:

Typical specification are measured at $V_{DD} = 3.0V$

Input sound pressure $P_{IN} = 94$ dB SPL@1kHZ

Test room temperature Ta = 25 °C, Room Humidity = $50 \pm 20\%$

SNR & noise floor measurement is based on 20 - 20 KHz pass band with A-Weighting

Filter applied

PERFORMANCE					
Parameter	Conditions	Min	Тур	Max	Unit
Directivity		Omni-I	Direction	al	
Sensitivity	@1KHz (0 dB = 1V/Pa)	-45	-42	-39	dB
Signal-to-Noise Ratio	@1KHz (0 dB = $1V/Pa$)		58		dB
Total Harmonic Distortion (THD) @ 100dB SPL	@1KHz		0.2	0.5	%
Total Harmonic Distortion (THD) @ 115dB SPL	@1KHz		0.5	1	%
Max Input Sound Pressure	@1KHz, THD < 10%		130		dB SPL
Power Supply Rejection (PSR)	217Hz,100m Vpp square wave		-84	-79	dB
	INPUT CHARACTERISTIC	CS			
Power supply Voltage		1.6		3.6	V
Sensitivity Loss Across Power Supply Voltage	Change in sensitivity from 1.6V to 3.6V power supply voltage	No cha	nge		dB
Total Operation Current	1.6V-3.6V power supply voltage		160	200	uA
Standby Current	1.6V-3.6V power supply voltage			2	uA
OUTPUT CHARACTERISTICS					
Output Impedance	@1KHz (0 dB = 1 V/Pa)			200	Ω

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Figure 1. Typical free field frequency response (Normalized to 1 KHz)

<u>"H</u>"

5. MECHANICAL SPECIFICATIONS





ITEM	DIMENSION	TOLERANCE	UNITS		PIN OUTPUT
LENGTH(L)	3.76	± 0.10	mm	PIN#	FUNCTION
WIDTH(W)	2.24	±0.10	mm	1	POWER(Vdd)
HEIGHT(H)	1 10	+0.10	mm	2	GROUND
ACOUSTIC	1.10			3	GROUND
PORT(AP)	Φ0.50	± 0.10	mm	4	OUTPUT

(09)

m

R0.10

(4X)

Note:

Dimensions are in millimeters unless otherwise specified. Tolerance ± 0.15 mm unless otherwise specified

Figure 2. Detailed mechanical drawings

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6. RECOMMENDED CUSTOMER LANDING PATTERN



Figure 3. Recommended landing pattern on customers' PCB

7. RECOMMENDED INTERFACE CIRCUIT



Figure 4. Recommended interface circuit for customers' applications

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8. PACKAGING SPECIFICATIONS



D0	1.5 ± 0.1	W	12.0 ± 0.30
D1	1.5 ± 0.1	Е	1.75 ± 0.10
A0	4.06 ± 0.10	F	5.50 ± 0.10
B0	2.54 ± 0.10	PO	4.00 ± 0.10
K0	1.35 ± 0.10	P1	8.0 ± 0.10
Т	0.3±0.05	P2	2.00±0.10

Notes:

(1) Tape & Reel Per EIA-481 standard;

(2) Label applied to external package and direct to reel

Order Part Number	Reel Diameter	Qty per Reel
NSM2402AT	13"	5,000

Figure 5. Tape Specification

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SPEC	13"
$C1 \pm 1.0$	Ф330
$A \pm 0.2$	2.6
B±0.2	10.8
T±0.2	2.0

Available Reel Size(mm)			
Tape Width	$D\pm0.5$	H+1	
12	Φ100	12.5	

5,000PCS PRODUCTS/1 reel

Figure 6. Reel Specification

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50,000 Pieces of Products per Carton

Figure 7. Packaging Specification

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9. SOLDER REFLOW PROFILE



Profile Feature	Pb-Free
Average Ramp-up rate (T _{SMAX} to T _P)	3°C/second max.
Preheat	
Temperature Min (T _{SMIN})	150°C
Temperature Max (T _{SMAX})	200°C
Time $(T_{SMIN} \text{ to } T_{SMAX})(t_S)$	60-180 seconds
Time maintained above:	
Temperature (T _L)	217°C
Time (t_L)	60-150 seconds
Peak Temperature (T _P)	260°C
Time within 5 $^{\circ}$ C of actual Peak Temperature (t _P)	20-40 seconds
Ramp-down rate(T_P to T_{SMAX})	6°C/second max
Time 25°C to Peak Temperature	8 minutes max

Figure 8. Recommended leadless solder reflow temperature profile

Notes:

- 1. Vacuuming over acoustical hole of the microphone is not allowed, because the Devices can be damaged by vacuum.
- 2. Washing the board after reflow process is not allowed, because board washing and Cleaning agents can damage the device. A device should not be exposed to ultrasonic processing or cleaning.
- 3. Recommended number of reflow is no more than 5 Times.

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10. RELIABILITY SPECIFICATIONS

Test item	Detail	standard
Reflow Simulation	Refer to Sec.9 for solder reflow profile, total 5 times	/
Low Temperature Bias	Conditions:-40°C Duration:168 hours while under bias	IEC 60068-2-2 Test Aa
High Temperature Bias	Conditions: 105°C Duration:168 hours while under bias	IEC 60068-2-2 Test Ba
Thermal Shock	Conditions: 100 cycles of air-air thermal shock from -40 °C to 125 °C with 15-minute soaks	IEC 60068-2-4
Temperature/Humidity Bias	Conditions: 85°C/85%RH environment while under bias for 168 hours	JESD 22-A101A-B
Mechanical Shock	Conditions:3 pulses of 10,000g in the X,Y and Z direction	IEC 60068-2-27 Test Ea
Vibration Test	Test axis: X, Y, Z Conditions : 2~400Hz 1 oct/min Test time : 15 mins per axis Use fixture during the testing	IEC 60068-2-6
Drop Test	Conditions: For each sample, drop by all corners, edges, surfaces respectively. Steel floor. Drop height: 1800mm.	IEC 60068-2-32
ESD	Conditions: \pm 8KV direct contact to the lid when unit is grounded , \pm 4KV direct contact to the I/O pins.10 times	IEC 61000-4-2

Note: Immediately after reliability test, the samples shall be stored under climatic conditions such as that normally exist in ordinary rooms or laboratories. Unless otherwise noted, the recovery period shall be 2 hours at least before performance testing after test condition is performed, the sensitivity of the microphone shall not deviate more than 3dB from its initial value.

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11. REVISION HISTORY:

Version	Date	Description	Change from	Change to
1.0	08/09/2011	Initial release		
1.1	06/06/2012	Updated the dimension of cap		
1.2	14/06/2012	Update mechanical specification and Solder reflow profile		
1.3	02/07/2012	Updated Reel specification		
1.4	20/08/2012	Updated Vibration Test		
1.5	10/10/2012	Updated absolute maximum ratings		
1.6	27/02/2013	 Section4 unit dBFS change to dB Update metal cap dimension Delete the dimension not related to the specifications marked in packaging Updated Mechanical Shock Updated Drop Test. 	2.12mm×3.66mm JEC 60068-2-27	2.06 mm×3.60mm IEC 60068-2-27
1.7	10/05/2013	Updated solder reflow profile		
1.8	03/06/2013	Updated section 7		
1.9	19/07/2013	Updated section 8 packaging specification		
2.0	17/01/2014	Updated test voltage		
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